2SC3611

Silicon NPN epitaxial planar type

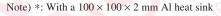
For video amplifier

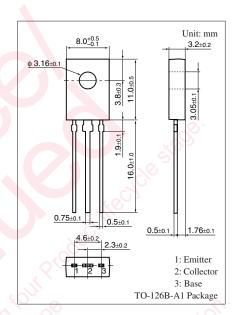
■ Features

- High transition frequency f_T
- Small collector output capacitance (Common base, input open circuited) C_{ob}
- Wide current range
- TO-126B package which requires no insulation plate for installation to the heat sink

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | |
|---------------------------------------|------------------|-------------|-------|--|
| Collector-base voltage (Emitter open) | V_{CBO} | 110 | V | |
| Collector-emitter voltage | V _{CER} | 100 | V | |
| (Resistor between B and E) | | | | |
| Collector-emitter voltage (Base open) | V _{CEO} | 50 | V | |
| Emitter-base voltage (Collector open) | V _{EBO} | 3.5 | V | |
| Collector current | I_{C} | 150 | mA | |
| Peak collector current | I_{CP} | 300 | mA | |
| Collector power dissipation | P _C | 1.2 | W | |
| | | 4.0 * | · Ale | |
| Junction temperature | T_{j} | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C 🛇 | |



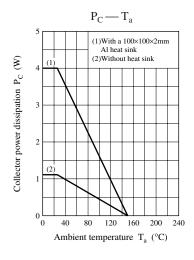


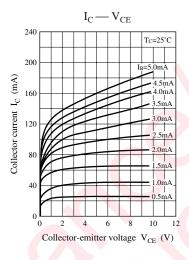
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

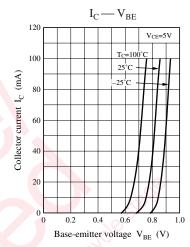
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|---|-----|-----|-----|------|
| Collector-base voltage (Emitter open) | V _{CBO} | $I_C = 100 \mu\text{A}, I_E = 0$ | 110 | | | V |
| Collector-emitter voltage (Resistor between B and E) | V _{CER} | $I_C = 500 \ \mu A, R_{BE} = 470 \ \Omega$ | 100 | | | V |
| Collector-emitter voltage (Base open) | V _{CEO} | $I_C = 1 \text{ mA}, I_B = 0$ | 50 | | | V |
| Emitter-base voltage (Collector open) | V _{EBO} | $I_E = 100 \mu\text{A}, I_C = 0$ | 3.5 | | | V |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{CE} = 35 \text{ V}, I_{B} = 0$ | | | 10 | μΑ |
| Forward current transfer ratio | h _{FE} | $V_{CE} = 5 \text{ V}, I_{C} = 100 \text{ mA}$ | 20 | | | _ |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | | 0.5 | V |
| Transition frequency | f _{T1} | $V_{CB} = 10 \text{ V}, I_E = -10 \text{ mA}, f = 200 \text{ MHz}$ | | 300 | | MHz |
| | f _{T2} | $V_{CB} = 10 \text{ V}, I_E = -110 \text{ mA}, f = 200 \text{ MHz}$ | | 350 | | |
| Collector output capacitance (Common base, input open circuited) | C _{ob} | $V_{CB} = 30 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ | | 3 | | pF |

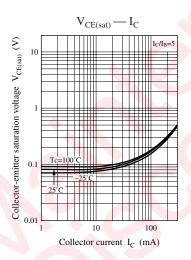
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

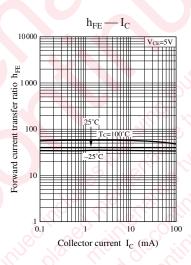
Publication date: January 2003 SJD00108BED 1

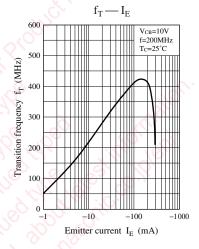


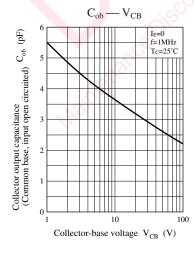


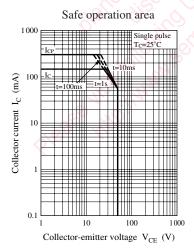




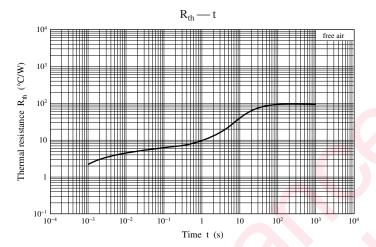








2 SJD00108BED



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